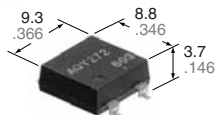
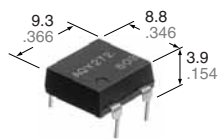


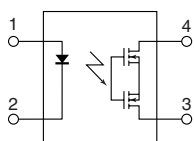
**Panasonic**  
ideas for life

**High capacity  
(Load current Max. 2A).  
Flat-Packaged type DIP  
(1Form A) 4-pin type.**

**PD PhotoMOS  
(AQY270)**



mm inch



**FEATURES**

**1. Flat-Packaged Type (W) 8.8× (D) 9.3× (H) 3.9mm (W) .346× (D) .366× (H) .154inch**

**2. High capacity**  
Supports the various types of load control, from very small loads to a maximum 2A at the rated load voltage 60V (AQY272)

**3. High sensitivity**  
• Low ON resistance  
A maximum 2A load can be controlled with a 5mA input current. The ON resistance is low at 0.11Ω (AQY272)

**TYPICAL APPLICATIONS**

- Measuring and Testing equipment
- IC Testers and Board Testers
- High speed inspection machines

**RoHS Directive compatibility information**  
<http://www.mew.co.jp/ac/e/environment/>

**TYPES**

Type	Output rating*		Part No.				Packing quantity	
	Load voltage	Load current	Through hole terminal	Surface-mount terminal			Tube	Tape and reel
			Tube packing style	Tape and reel packing style				
				Picked from the 1/2-pin side	Picked from the 3/4-pin side			
AC/DC	60V	2.0A	AQY272	AQY272A	AQY272AX	AQY272AZ	1 tube contains 50 pcs. 1 batch contains 1,000 pcs.	1,000 pcs.
	100V	1.3A	AQY275	AQY275A	AQY275AX	AQY275AZ		
	200V	0.65A	AQY277	AQY277A	AQY277AX	AQY277AZ		
	400V	0.35A	AQY274	AQY274A	AQY274AX	AQY274AZ		

\* Indicate the peak AC and DC values.  
Note: For space reasons, the SMD terminal shape indicator "A" and the package style indicator "X" or "Z" are not marked on the relay.

**RATING**

1. Absolute maximum ratings (Ambient temperature: 25°C 77°F)

Item	Symbol	AQY272(A)	AQY275(A)	AQY277(A)	AQY274(A)	Remarks	
Input	LED forward current	I <sub>F</sub>	50 mA				
	LED reverse voltage	V <sub>R</sub>	5 V				
	Peak forward current	I <sub>FP</sub>	1 A				f = 100 Hz, Duty factor = 0.1%
	Power dissipation	P <sub>in</sub>	75 mW				
Output	Load voltage (peak AC)	V <sub>L</sub>	60 V	100 V	200 V	400 V	
	Continuous load current (Peak AC)	I <sub>L</sub>	2.0 A	1.3 A	0.65 A	0.35 A	
	Peak load current	I <sub>peak</sub>	6.0 A	4.0 A	2.0 A	1.0 A	100ms (1 shot), V <sub>L</sub> = DC
	Power dissipation	P <sub>out</sub>	700 mW				
Total power dissipation	P <sub>T</sub>	750 mW					
I/O isolation voltage	V <sub>iso</sub>	2,500 V AC					
Temperature limits	Operating	T <sub>opr</sub>	-40°C to +85°C -40°F to +185°F				Non-condensing at low temperatures
	Storage	T <sub>stg</sub>	-40°C to +100°C -40°F to +212°F				

# PD PhotoMOS (AQY27○)

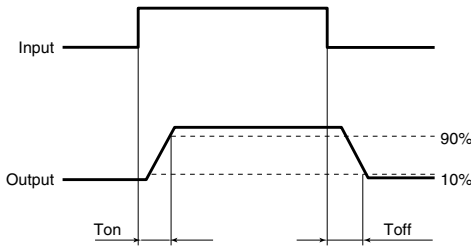
## 2. Electrical characteristics (Ambient temperature: 25°C 77°F)

Item		Symbol	AQY272(A)	AQY275(A)	AQY277(A)	AQY274(A)	Condition
Input	LED operate current	Typical	1.0 mA				$I_L = 100 \text{ mA}$ $V_L = 10 \text{ V}$
		Maximum	3.0 mA				
	LED turn off current	Minimum	0.4 mA				$I_L = 100 \text{ mA}$ $V_L = 10 \text{ V}$
		Typical	0.9 mA				
LED dropout voltage	Typical	1.25 V (1.16 V at $I_F = 10 \text{ mA}$ )				$I_F = 50 \text{ mA}$	
	Maximum	1.5 V					
Output	On resistance	Typical	0.11 $\Omega$	0.23 $\Omega$	0.7 $\Omega$	2.1 $\Omega$	$I_F = 10 \text{ mA}$ $I_L = \text{Max.}$ Within 1 s on time
		Maximum	0.18 $\Omega$	0.34 $\Omega$	1.1 $\Omega$	3.2 $\Omega$	
	Off state leakage current	Maximum	10 $\mu\text{A}$				$I_F = 0 \text{ mA}$ $V_L = \text{Max.}$
Transfer characteristics	Turn on time*	Typical	2.46 ms	2.40 ms	1.12 ms	1.65 ms	$I_F = 10 \text{ mA}$ $I_L = 100 \text{ mA}$ $V_L = 10 \text{ V}$
		Maximum	5.0 ms				
		Typical	5.64 ms	5.65 ms	2.57 ms	3.88 ms	
		Maximum	10.0 ms				
	Turn off time*	Typical	0.22 ms	0.21 ms	0.10 ms	0.08 ms	$I_F = 5 \text{ mA or } 10 \text{ mA}$ $I_L = 100 \text{ mA}$ $V_L = 10 \text{ V}$
		Maximum	3.0 ms				
	I/O capacitance	Typical	0.8 pF				$f = 1 \text{ MHz}$
		Maximum	1.5 pF				$V_B = 0 \text{ V}$
Initial I/O isolation resistance	Minimum	1,000 M $\Omega$				500 V DC	
Maximum operating speed	Maximum	0.5 cps				$I_F = 10 \text{ mA}$ Duty factor = 50% $I_L = \text{Max.}, V_L = \text{Max.}$	

Note: Recommendable LED forward current  $I_F = 5$  to 10 mA.

For type of connection.

\*Turn on/Turn off time

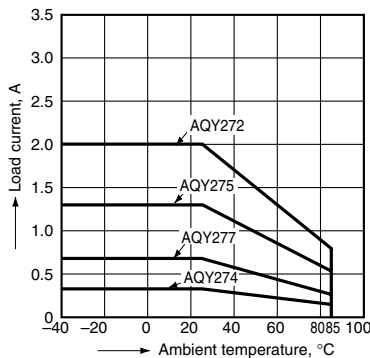


- For Dimensions.
- For Schematic and Wiring Diagrams.
- For Cautions for Use.

## REFERENCE DATA

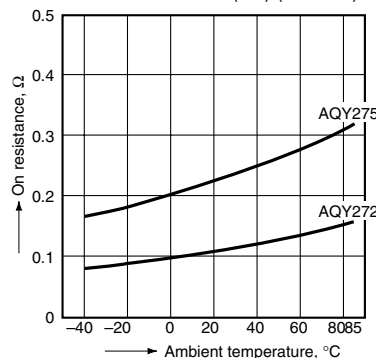
### 1. Load current vs. ambient temperature characteristics

Allowable ambient temperature: -40°C to +85°C  
-40°F to +185°F



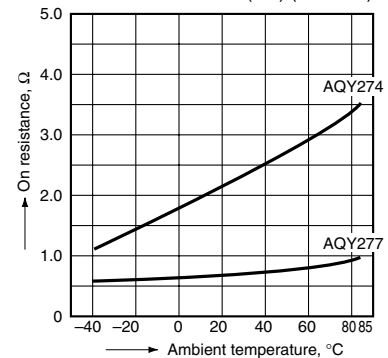
### 2.-(1) On resistance vs. ambient temperature characteristics

LED current: 10 mA;  
Continuous load current: 2.0 A (DC) (AQY272),  
1.3 A (DC) (AQY275)



### 2.-(2) On resistance vs. ambient temperature characteristics

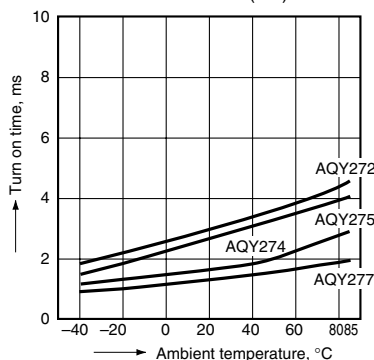
LED current: 10 mA;  
Continuous load current: 0.65 A (DC) (AQY277),  
0.35 A (DC) (AQY274)



# PD PhotoMOS (AQY27○)

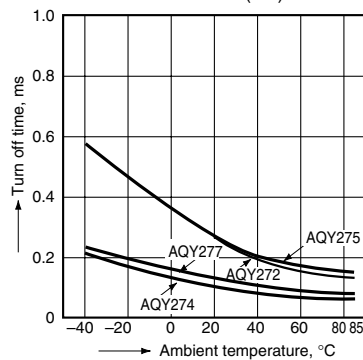
### 3. Turn on time vs. ambient temperature characteristics

LED current: 10 mA; Load voltage: 10 V (DC);  
Continuous load current: 100 mA (DC)



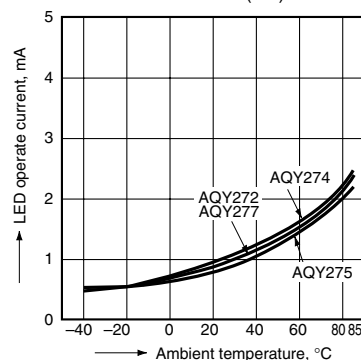
### 4. Turn off time vs. ambient temperature characteristics

LED current: 10 mA; Load voltage: 10 V (DC);  
Continuous load current: 100 mA (DC)



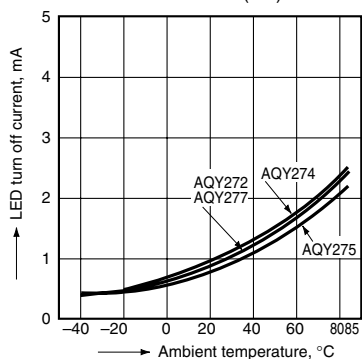
### 5. LED operate vs. ambient temperature characteristics

Load voltage: 10 V (DC);  
Continuous load current: 100 mA (DC)



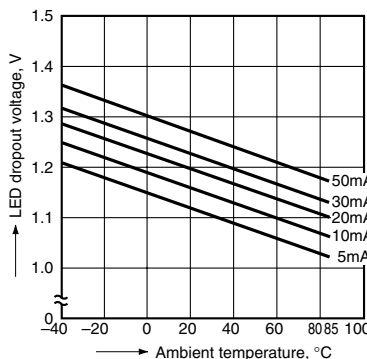
### 6. LED turn off current vs. ambient temperature characteristics

Load voltage: 10 V (DC);  
Continuous load current: 100 mA (DC)



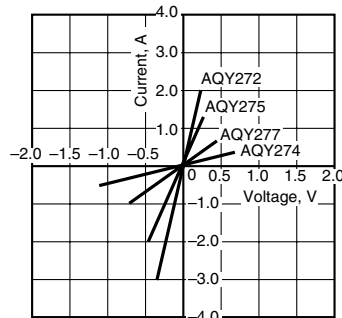
### 7. LED dropout voltage vs. ambient temperature characteristics

Sample: all types;  
LED current: 5 to 50 mA



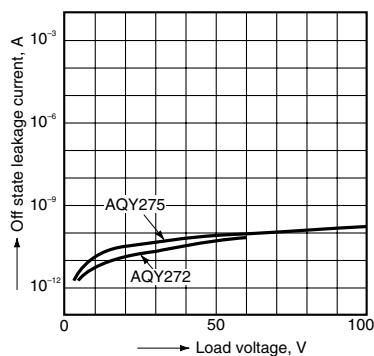
### 8. Current vs. voltage characteristics of output at MOS portion

Ambient temperature: 25°C 77°F



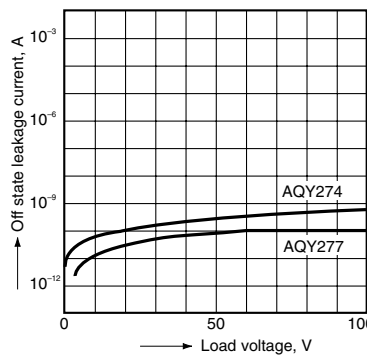
### 9.-(1) Off state leakage current vs. load voltage characteristics

Ambient temperature: 25°C 77°F



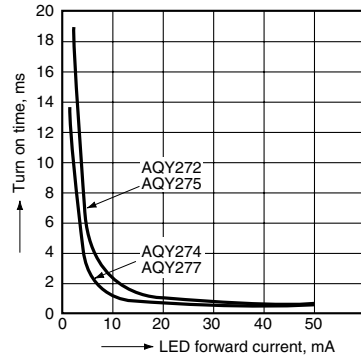
### 9.-(2) Off state leakage current vs. load voltage characteristics

Ambient temperature: 25°C 77°F



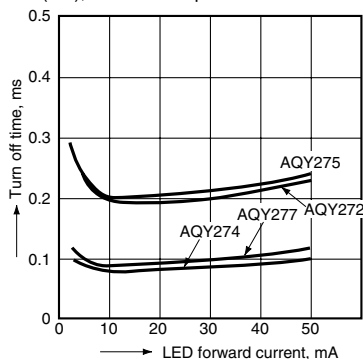
### 10. Turn on time vs. LED forward current characteristics

Load voltage: 10 V (DC); Continuous load current: 100 mA (DC); Ambient temperature: 25°C 77°F



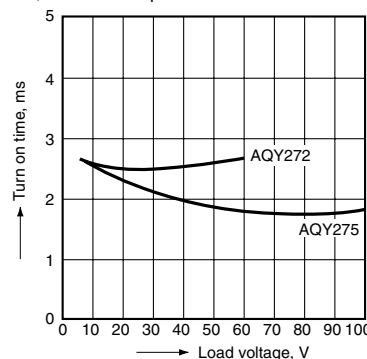
### 11. Turn off time vs. LED forward current characteristics

Load voltage: 10 V (DC); Continuous load current: 100 mA (DC); Ambient temperature: 25°C 77°F



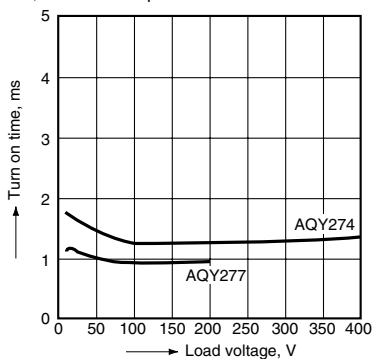
### 12.-(1) Turn on time vs. load voltage characteristics

LED current: 10 mA; Continuous load current: 100 mA; Ambient temperature: 25°C 77°F



### 12.-(2) Turn on time vs. load voltage characteristics

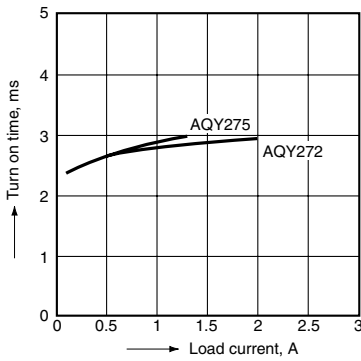
LED current: 10 mA; Continuous load current: 100 mA; Ambient temperature: 25°C 77°F



# PD PhotoMOS (AQY27○)

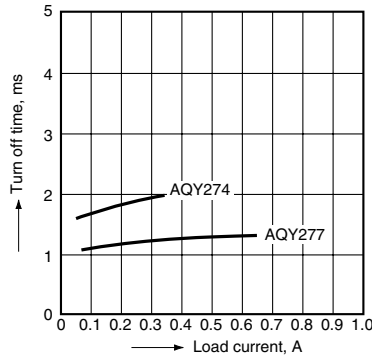
13.-(1) Turn on time vs. load current characteristics

LED current: 10 mA; Load voltage: 10 V (DC); Ambient temperature: 25°C 77°F



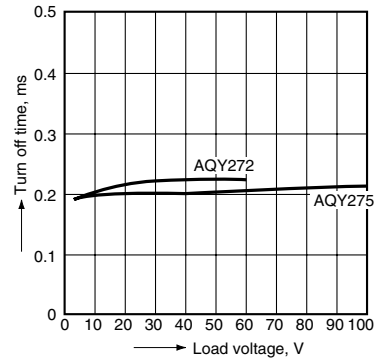
13.-(2) Turn on time vs. load current characteristics

LED current: 10 mA; Load voltage: 10 V (DC); Ambient temperature: 25°C 77°F



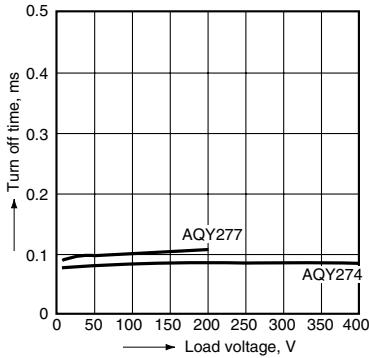
14.-(1) Turn off time vs. load voltage characteristics

LED current: 10 mA; Continuous load current: 100 mA; Ambient temperature: 25°C 77°F



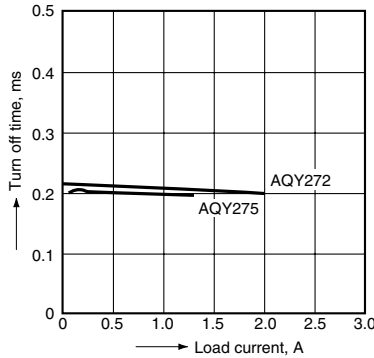
14.-(2) Turn off time vs. load voltage characteristics

LED current: 10 mA; Continuous load current: 100 mA; Ambient temperature: 25°C 77°F



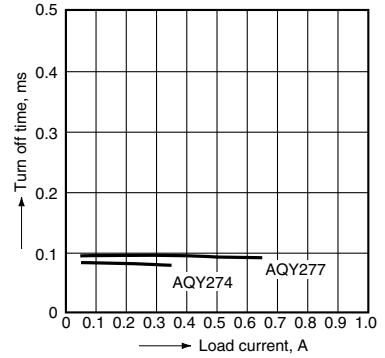
15.-(1) Turn off time vs. load current characteristics

LED current: 10 mA; Load voltage 10 V (DC); Ambient temperature: 25°C 77°F



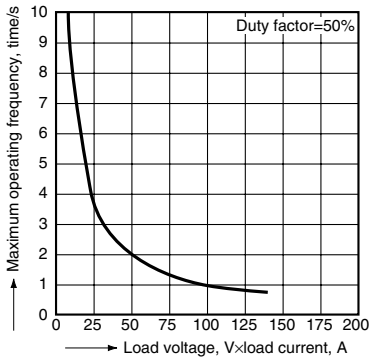
15.-(2) Turn off time vs. load current characteristics

LED current: 10 mA; Load voltage 10 V (DC); Ambient temperature: 25°C 77°F



16. Maximum operating frequency vs. load voltage/current characteristics

LED current: 10 mA; Ambient temperature: 25°C 77°F



17. Output capacitance vs. applied voltage characteristics

Frequency: 1 MHz; Ambient temperature: 25°C 77°F

